

January 7, 1998

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AXIAL LEADED HERMETICALLY SEALED SUPERFAST RECTIFIER DIODE

QUICK REFERENCE DATA

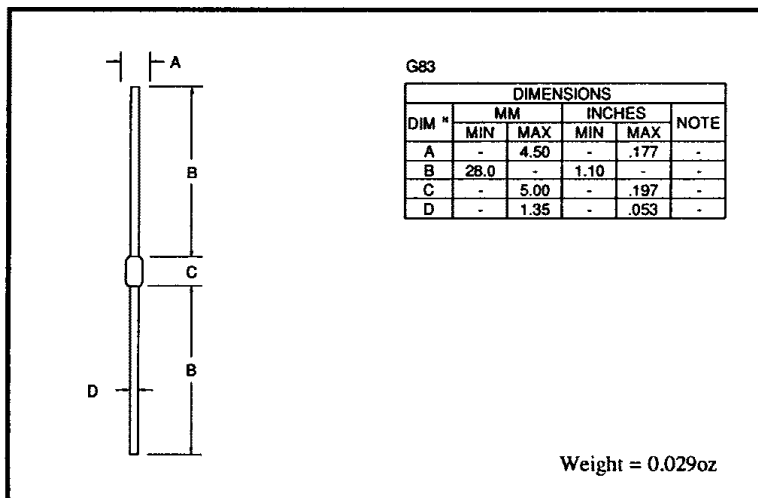
- Very low reverse recovery time
- Low forward voltage drop
- Glass passivated for hermetic sealing
- Low switching losses
- Soft, non-snap off, recovery characteristics

- $V_R = 50 - 200V$
- $I_F = 4.0A$
- $t_{rr} = 30ns$
- $V_F = 1.05V$

ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

| | Symbol | 3PFT05 | 3PFT1 | 3PFT15 | 3PFT2 | Unit |
|--|-------------|-----------------|-------|--------|-------|------|
| Working reverse voltage | V_{RWM} | 50 | 100 | 150 | 200 | V |
| Repetitive reverse voltage | V_{RRM} | 50 | 100 | 150 | 200 | V |
| Average forward current (@ 55°C, lead length 0.375") | $I_{F(AV)}$ | ← 4.0 → | | | | A |
| Repetitive surge current (@ 55°C in free air, lead length 0.375") | I_{FRM} | ← 25 → | | | | A |
| Non-repetitive surge current ($t_p = 8.3ms$, @ V_R & T_{jmax}) | I_{FSM} | ← 90 → | | | | A |
| Storage temperature range | T_{STG} | ← -65 to +175 → | | | | °C |
| Operating temperature range | T_{OP} | ← -65 to +175 → | | | | °C |

MECHANICAL



These products are qualified in Europe to DEF STAN 59-61 (PART 80)/029 available to F and FX levels.

January 7, 1998

ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified)

| | Symbol | 3PFT05 | 3PFT1 | 3PFT15 | 3PFT2 | Unit |
|--|--------------------|----------|-------|--------|-------|------------------|
| Average forward current max. (pcb mounted; T _A = 55°C) for sine wave | I _{F(AV)} | ← 1.8 → | | | | A |
| | I _{F(AV)} | ← 1.9 → | | | | A |
| Average forward current max. (T _L = 55°C; L = 3/8") for sine wave | I _{F(AV)} | ← 3.8 → | | | | A |
| | I _{F(AV)} | ← 4.0 → | | | | A |
| I ² t for fusing (t = 8.3mS) max. | I ² t | ← 33 → | | | | A ² S |
| Forward voltage drop max. @ I _F = 3.5A, T _j = 25°C | V _F | ← 1.05 → | | | | V |
| Reverse current max. @ V _{RWM} , T _j = 25°C | I _R | ← 1.0 → | | | | μA |
| | I _R | ← 10 → | | | | μA |
| Reverse recovery time max. 0.5A I _F to 1.0A I _R . Recovers to 0.25A I _{RR} . | t _{rr} | ← 30 → | | | | nS |
| Junction capacitance typ. @ V _R = 5V, f = 1MHz | C _j | ← 92 → | | | | ρF |

THERMAL CHARACTERISTICS

| | Symbol | 3PFT05 | 3PFT1 | 3PFT15 | 3PFT2 | Unit |
|--|------------------|--------|-------|--------|-------|------|
| Thermal resistance - junction to lead Lead length = 0.375" | R _{θJL} | ← 26 → | | | | °C/W |
| | R _{θJL} | ← 12 → | | | | °C/W |
| Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper. | R _{θJA} | ← 75 → | | | | °C/W |

January 7, 1998

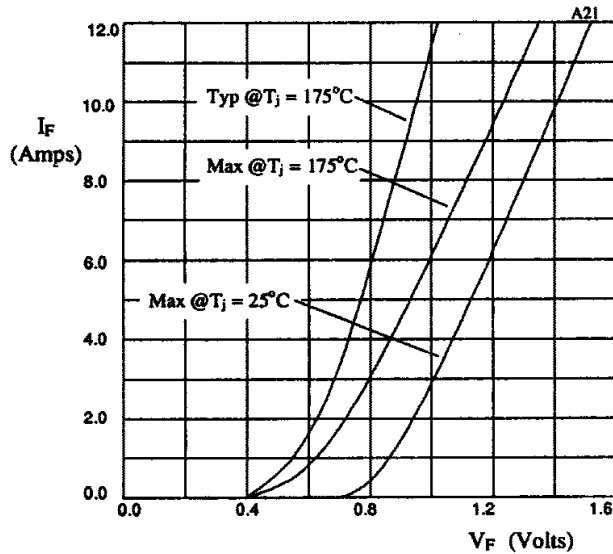


Fig 1. Forward voltage drops as a function of forward current.

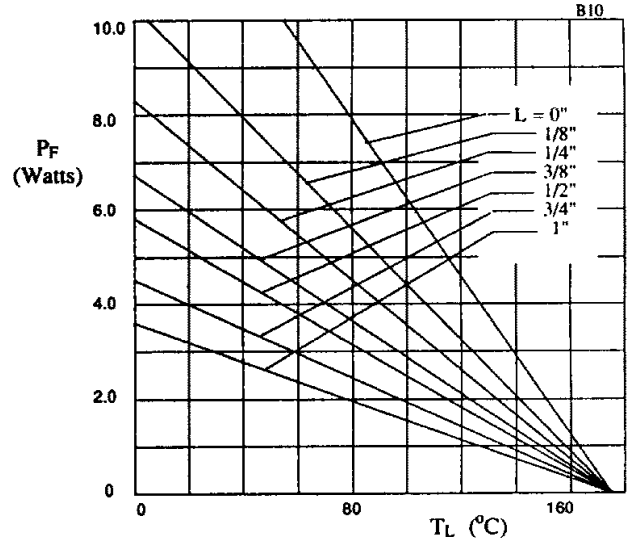


Fig 2. Maximum power versus lead temperature.

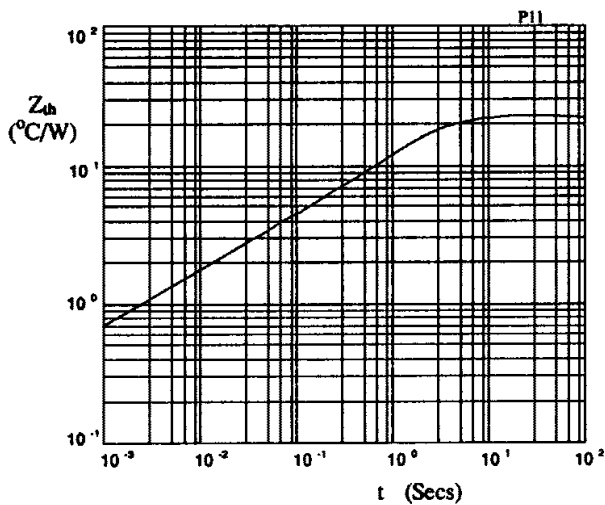


Fig 3. Transient thermal impedance characteristic.

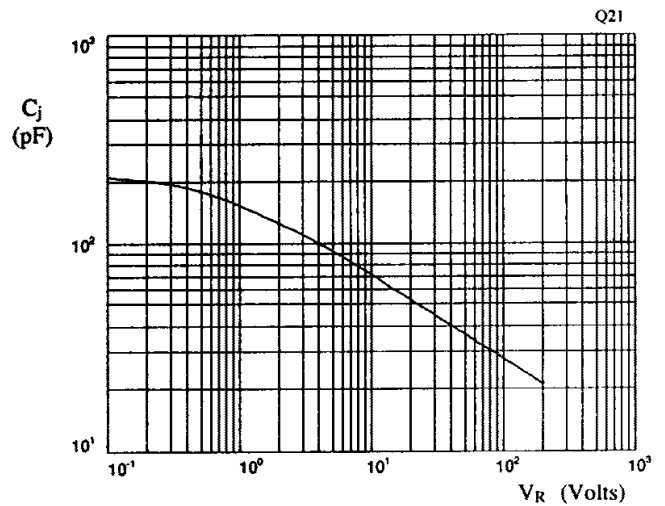


Fig 4. Typical junction capacitance as a function of reverse voltage.

January 7, 1998

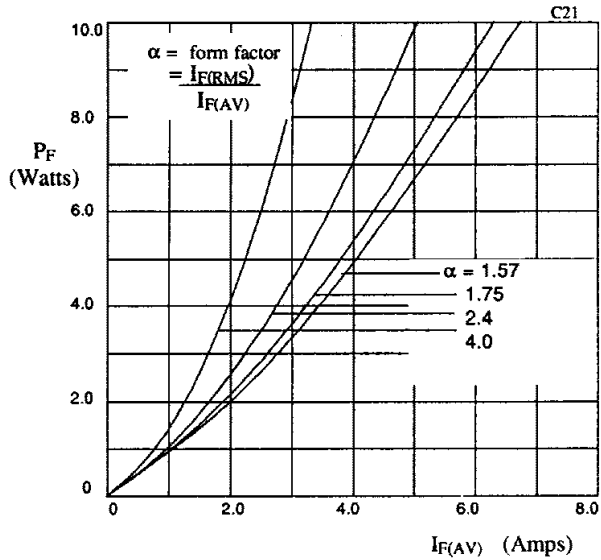


Fig 5. Forward power dissipation as a function of forward current, for sinusoidal operation.

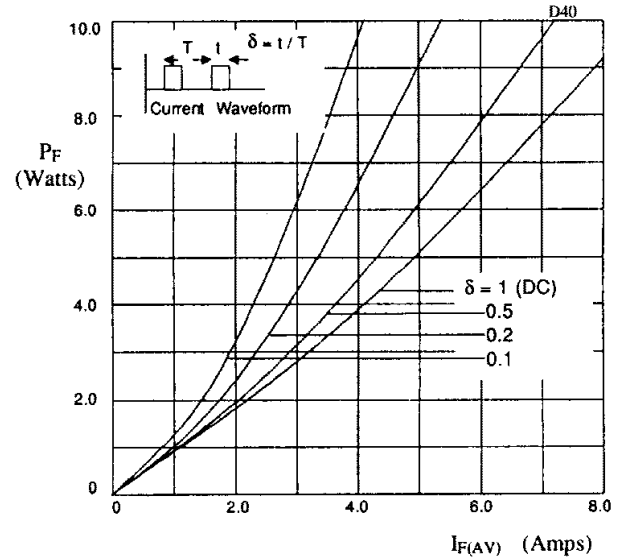


Fig 6. Forward power dissipation as a function of forward current, for square wave operation.

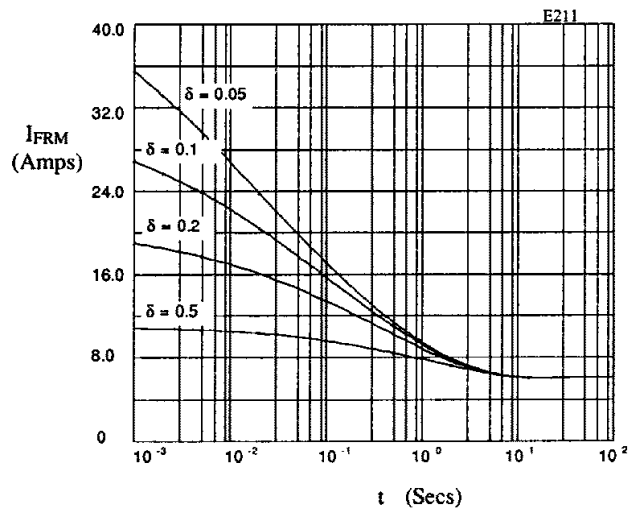


Fig 7. Typical repetitive forward current as a function of pulse width at 55°C; $R_{\theta JL} = 22^\circ\text{C/W}$; V_{RWM} during $1 - \delta$.

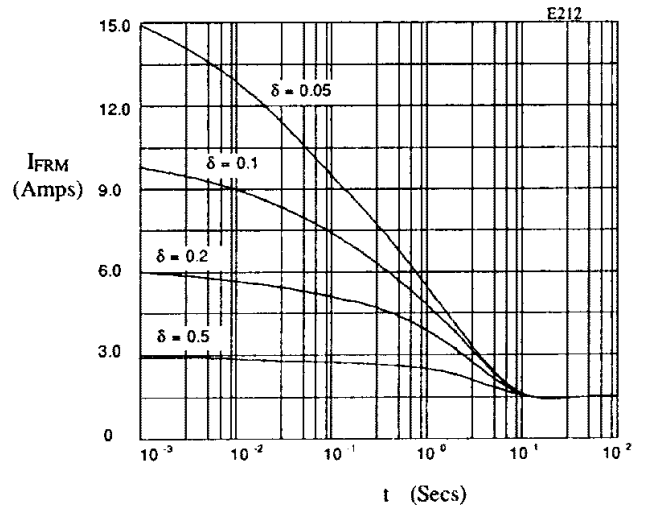


Fig 8. Typical repetitive forward current as a function of pulse width at 100°C; $R_{\theta JL} = 75^\circ\text{C/W}$; V_{RWM} during $1 - \delta$.